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Comparison of surface relief Bragg gratings fabricated by UV-SCIL and volume index Bragg gratings based on hybrid polymers

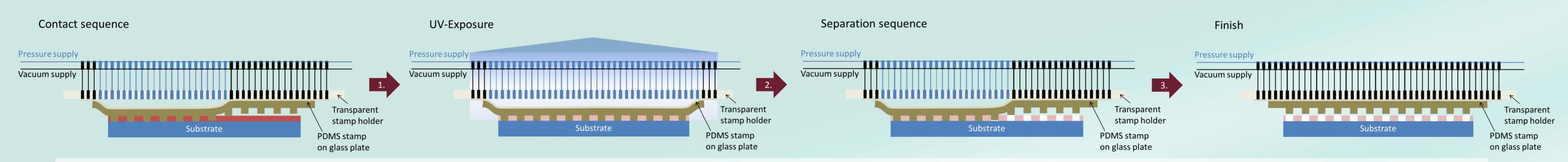
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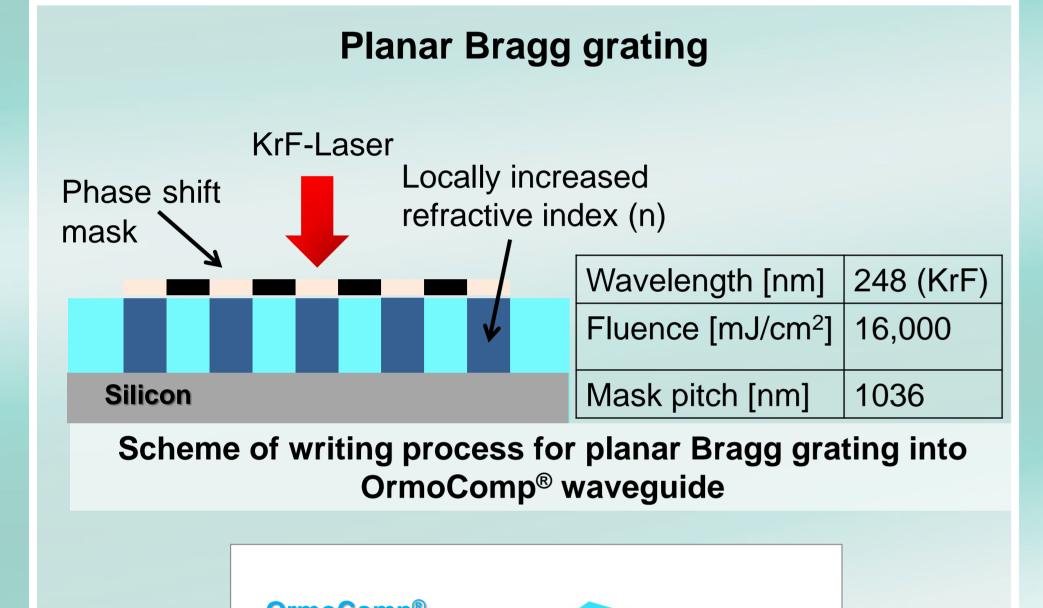
Introduction

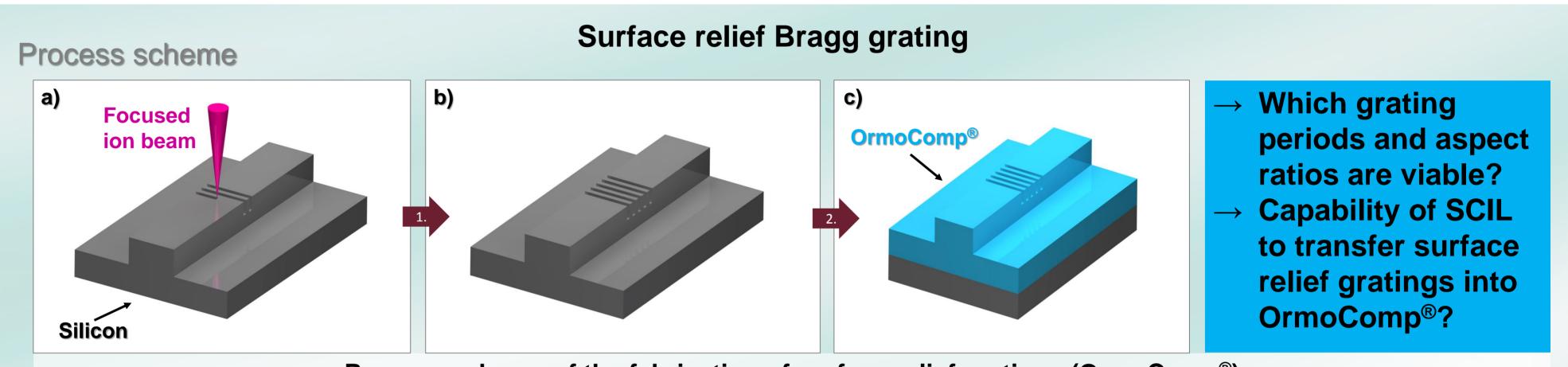
- Hybrid polymers show high potential for optical device fabrication [1].
- \checkmark Viable for usage in lab-on-a-chip systems [1].
- UV-SCIL as low cost and high precision patterning technique for wafer scale solutions [2].
- ✓ Planar and surface relief Bragg gratings fabricatable in OrmoComp[®] by UV-SCIL.
- \checkmark Planar grating type for high quality signals.
- ✓ Surface relief gratings created in silicon master by ion beam treatment for fast and flexible prototyping of specific grating periods and depths.
- ✓ Surface relief Bragg gratings enable direct structuring of optical devices including

Scheme of the UV-SCIL-process



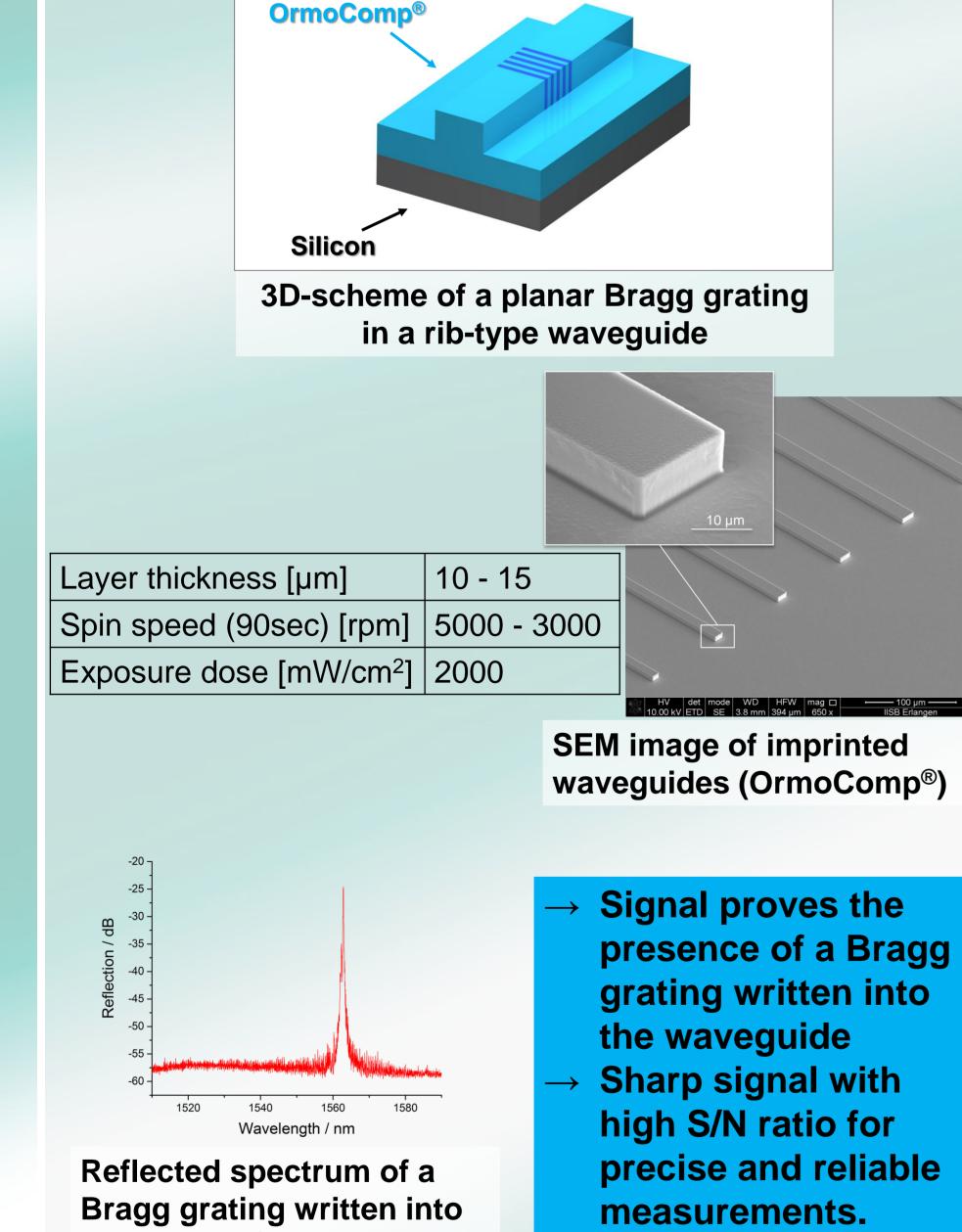
Process flow of UV-SCIL Nanoimprint process. For both grating types a three layer hybrid stamp was used containing a X-PDMS top layer for a high aspect structure transfer.



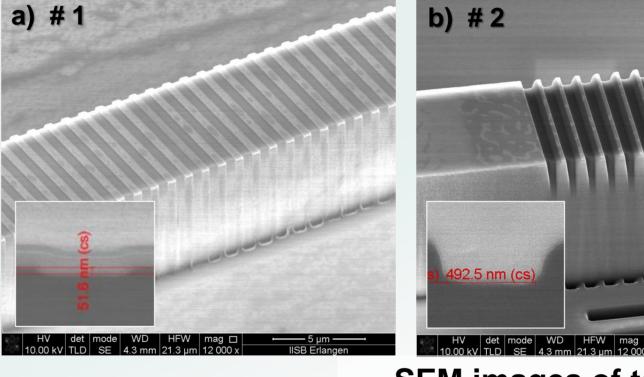


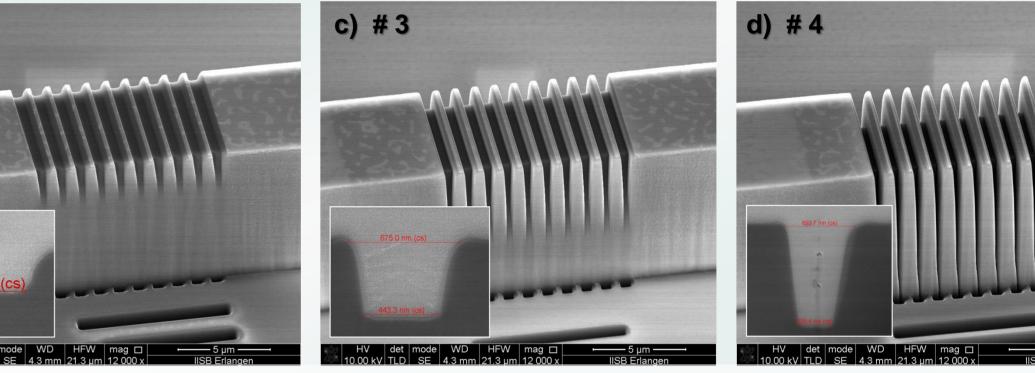
Process scheme of the fabrication of surface relief gratings (OrmoComp[®])

a) FIB milling of gratings in etched silicon waveguide structures b) surface relief grating for stamp manufacturing c) transferred surface relief grating imprinted on a silicon substrate



Test pattern Gratings with a pitch of 1064 nm and depths varying from 25 nm up to 2.5 µm were implemented on silicon masters using focused ion beam (FIB) milling.

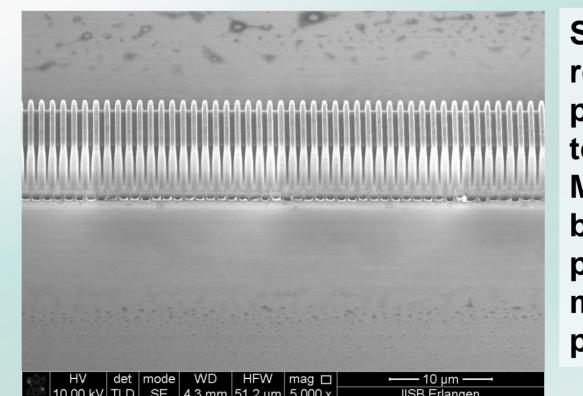




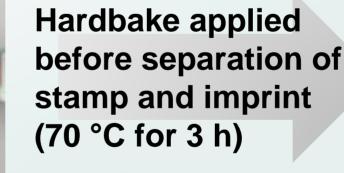
SEM images of test patterns including cross sections shown in the inset: a) aspect ratio ~ 0.01 b) aspect ratio ~ 0.5 c) aspect ratio ~ 1 d) aspect ratio ~ 2

Applied ion beam parameters				
Pattern #	1	2	3	4
Dose [1/cm ²]	1 x 10 ¹⁷	5 x 10 ¹⁷	1 x 10 ¹⁸	2 x 10 ¹⁸
Current [pA]	93	93	93	93
Aspect ratio	~ 0.01	~ 0.5	~ 1	~ 2

Fabrication of Bragg gratings



SEM image of fabricated relief gratings having pattern type # 3 and a total length of 400 µm. Manual stitching between single writing processes led to no measurable shift in the periodicity.



Imprinted test patterns with and without hardbake

Collapsing of imprinted

- gratings for aspect ratios > 2
- → Gratings stabilized by hardbake
- → Increased Young's modulus



SEM (left) and optical microscope (top) image of replicated surface relief grating from pattern type # 3. No defect or structure collapse visible over the whole length.

Conclusions and Outlook

In <u>conclusion</u>, this work presents two concepts to produce Bragg gratings using hybrid polymers combined with UV-SCIL.

- ✓ Planar Bragg gratings: more steps needed to produce devices. Also, they are restricted to the period of the phase mask, but show a clear and high Bragg reflection.
- Surface relief Bragg gratings: are flexible in production concerning the grating period and no additional exposure step is needed after the imprint to create a device. The focused ion beam milling is connected to a high effort to achieve a sufficing length of the Bragg grating.

As an outlook, surface relief Bragg gratings will be characterized and the performance will be compared to those of planar type Bragg gratings.

References

[1] Houbertz, R.; Domann, G.; Cronauer, C.; Schmitt, A.; Martin, H.; Park, J.-U.; Fröhlich, L.; Thin Solid Films 443 (2003) 194–200. [2] Verschuuren, M.A.; Substrate conformal imprint lithography for nanophotonics, PhD thesis, Utrecht University, 2010.

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